

MT29E512G08CEHBBJ4-3ES:B TR Information


For Reference Only

Part Number [MT29E512G08CEHBBJ4-3ES:B TR](#)
Manufacturer Micron Technology Inc.
Category Integrated Circuits (ICs)
Memory
Description IC FLASH 512GBIT 333MHZ 132VBGA
Package -
 For the pricing/inventory/lead time, please contact us
 Website: <https://www.heisener.com>
 E-mail: salesdept@heisener.com



[Request a Quote](#)

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.


MT29E512G08CEHBBJ4-3ES:B TR Specifications

Manufacturer Part Number	MT29E512G08CEHBBJ4-3ES:B TR
Manufacturer	Micron Technology Inc.
Category	Integrated Circuits (ICs) Memory
Package	-
Series	-
Memory Type	Non-Volatile
Memory Format	FLASH
Technology	FLASH - NAND
Memory Size	512Gb (64G x 8)
Memory Interface	Parallel
Clock Frequency	333MHz
Write Cycle Time - Word, Page	-
Access Time	-
Voltage - Supply	2.5 V ~ 3.6 V
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	-
Package / Case	-
Supplier Device Package	-

[Report errors?](#)

MT29E512G08CEHBBJ4-3ES:B TR Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

MT29E512G08CEHBBJ4-3ES:B TR Payment Methods



MT29E512G08CEHBBJ4-3ES:B TR Shipping Methods



If you have any question about MT29E512G08CEHBBJ4-3ES:B TR, please do not hesitate to contact us!

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